

LM2578A/LM3578A Switching Regulator

Check for Samples: LM2578A, LM3578A

FEATURES

- Inverting and Non-Inverting Feedback Inputs
- 1.0V Reference at Inputs
- Operates from Supply Voltages of 2V to 40V
- Output Current up to 750 mA, Saturation Less than 0.9V
- Current Limit and Thermal Shut Down
- Duty Cycle up to 90%

APPLICATIONS

- Switching Regulators in Buck, Boost, Inverting, and Single-Ended Transformer Configurations
- Motor Speed Control
- Lamp Flasher

DESCRIPTION

The LM2578A is a switching regulator which can easily be set up for such DC-to-DC voltage conversion circuits as the buck, boost, and inverting configurations. The LM2578A features a unique comparator input stage which not only has separate pins for both the inverting and non-inverting inputs, but also provides an internal 1.0V reference to each input, thereby simplifying circuit design and p.c. board layout. The output can switch up to 750 mA and has output pins for its collector and emitter to promote design flexibility. An external current limit terminal may be referenced to either the ground or the Vin terminal, depending upon the application. In addition, the LM2578A has an on board oscillator, which sets the switching frequency with a single external capacitor from <1 Hz to 100 kHz (typical).

The LM2578A is an improved version of the LM2578, offering higher maximum ratings for the total supply voltage and output transistor emitter and collector voltages.

Connection Diagram

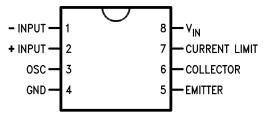
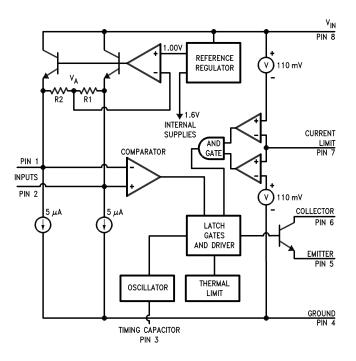


Figure 1. PDIP/SOIC Package See Package Number D0008A or P0008E

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Functional Diagram





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1)(2)

	<u> </u>			
Total Supply Voltage		50V		
Collector Output to Ground		-0.3V to +50V		
Emitter Output to Ground (3)		−1V to +50V		
Power Dissipation (4)		Internally limited		
Output Current				
Storage Temperature	-65°C			
Lead Temperature	(soldering, 10 seconds)	260°C		
Maximum Junction Tempera	ture	150°C		
ESD Tolerance (5)		2 kV		

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) For T_J ≥ 100°C, the Emitter pin voltage should not be driven more than 0.6V below ground (see Application Information).
- (4) At elevated temperatures, devices must be derated based on package thermal resistance. The device in the 8-pin DIP must be derated at 95°C/W, junction to ambient. The device in the SOIC package must be derated at 150°C/W, junction-to-ambient.
- (5) Human body model, $1.5 \text{ k}\Omega$ in series with 100 pF.

Operating Ratings

Ambient Temperature Range	LM2578A	-40°C ≤ T _A ≤+85°C
	LM3578A	0°C ≤ T _A ≤+70°C
Junction Temperature Range	LM2578A	-40°C ≤ T _J ≤+125°C
	LM3578A	0°C ≤ T _J ≤+125°C



Electrical Characteristics

These specifications apply for $2V \le V_{IN} \le 40V$ (2.2V $\le V_{IN} \le 40V$ for $T_J \le -25^{\circ}C$), timing capacitor $C_T = 3900$ pF, and $25\% \le 0$ duty cycle $\le 75\%$, unless otherwise specified. Values in standard typeface are for $T_J = 25^{\circ}C$; values in **boldface type** apply for operation over the specified operating junction temperature range.

Symbol	Parameter	Conditions	Typical ⁽¹⁾	LM2578A/ LM3578A Limit ⁽²⁾	Units
OSCILLATO	R				
fosc	Frequency		20		kHz
				24	kHz (max)
				16	kHz (min)
Δf _{OSC} /ΔT	Frequency Drift with Temperature		-0.13		%/°C
	Amplitude		550		mV_{p-p}
REFERENCE	C/COMPARATOR (3)				
V_R	Input Reference	$I_1 = I_2 = 0 \text{ mA and}$	1.0		V
	Voltage	$I_1 = I_2 = 1 \text{ mA } \pm 1\%$ (4)		1.050/ 1.070	V (max)
$\Delta V_R/\Delta V_{IN}$ Input Reference Volt Regulation				0.950/ 0.930	V (min)
$\Delta V_R / \Delta V_{IN}$	Input Reference Voltage Line	$I_1 = I_2 = 0 \text{ mA and}$	0.003		%/V
	Regulation	$I_1 = I_2 = 1 \text{ mA } \pm 1\%$ (4)		0.01/ 0.02	%/V (max)
I _{INV}	Inverting Input Current	$I_1 = I_2 = 0$ mA, duty cycle = 25%	0.5		μΑ
	Level Shift Accuracy	Level Shift Current = 1 mA	1.0		%
				10/ 13	% (max)
ΔV _R /Δt	Input Reference Voltage Long Term Stability		100		ppm/1000h
OUTPUT					
V _C (sat)	Collector Saturation Voltage	I _C = 750 mA pulsed, Emitter	0.7		V
		grounded		0.90/ 1.2	V (max)
V _E (sat)	Emitter Saturation Voltage	I _O = 80 mA pulsed,	1.4		V
		$V_{IN} = V_C = 40V$		1.7/ 2.0	V (max)
I _{CES}	Collector Leakage Current	$V_{IN} = V_{CE} = 40V$, Emitter grounded,	0.1		μΑ
		Output OFF		200/ 250	μA (max)
BV _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	$I_{SUST} = 0.2A$ (pulsed), $V_{IN} = 0$	60		V
				50	V (min)
CURRENT LI	MIT				<u> </u>
V _{CL}	Sense Voltage Shutdown Level	Referred to V _{IN} or Ground	110		mV
02		See (5)		80	mV (min)
				160	mV (max)
ΔV _{CL} /ΔT	Sense Voltage Temperature Drift		0.3		%/°C
I _{CL}	Sense Bias Current	Referred to V _{IN}	4.0		μΑ
		Referred to ground	0.4		μA

⁽¹⁾ Typical values are for $T_J = 25^{\circ}C$ and represent the most likely parametric norm.

Product Folder Links: LM2578A LM3578A

⁽²⁾ All limits specified at room temperature (standard type face) and at temperature extremes (bold type face). Room temperature limits are 100% production tested. Limits at temperature extremes are specified via correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate AOQL.

⁽³⁾ Input terminals are protected from accidental shorts to ground but if external voltages higher than the reference voltage are applied, excessive current will flow and should be limited to less than 5 mA.

⁽⁴⁾ I₁ and I₂ are the external sink currents at the inputs (refer to Test Circuit).

⁵⁾ Connection of a 10 kΩ resistor from pin 1 to pin 4 will drive the duty cycle to its maximum, typically 90%. Applying the minimum Current Limit Sense Voltage to pin 7 will not reduce the duty cycle to less than 50%. Applying the maximum Current Limit Sense Voltage to pin 7 is certain to reduce the duty cycle below 50%. Increasing this voltage by 15 mV may be required to reduce the duty cycle to 0%, when the Collector output swing is 40V or greater (see Ground-Referred Current Limit Sense Voltage typical curve).



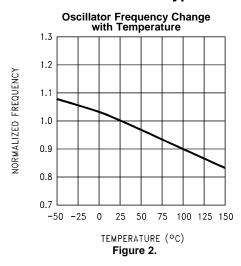
Electrical Characteristics (continued)

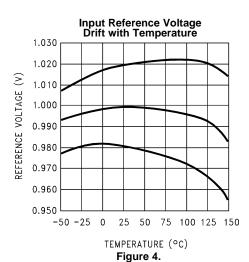
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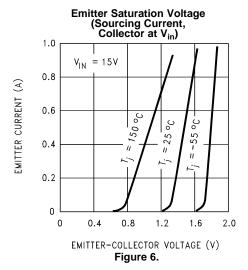
Symbol	Parameter	Conditions	Typical ⁽¹⁾	LM2578A/ LM3578A Limit ⁽²⁾	Units
DEVICE POW	ER CONSUMPTION				
Is	Supply Current	Output OFF, V _E = 0V	2.0		mA
				3.5/ 4.0	mA (max)
		Output ON, I _C = 750 mA pulsed,	14		mA
		V _E = 0V			

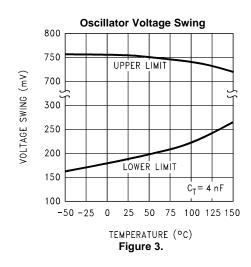


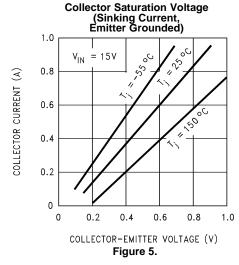
Typical Performance Characteristics

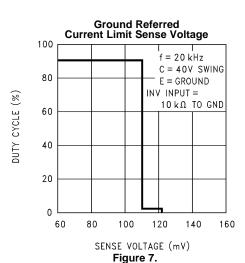






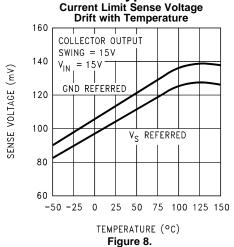


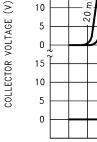


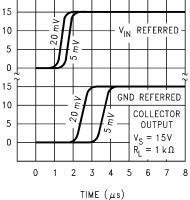




Typical Performance Characteristics (continued) Current Limit Response Time







for Various Over Drives

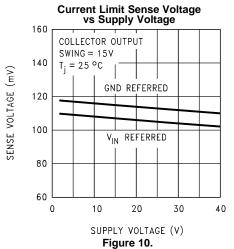
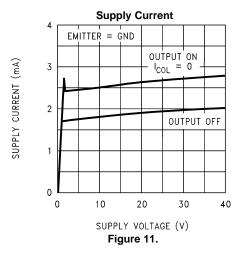
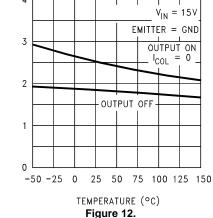


Figure 9.



Supply Current 4

SUPPLY CURRENT (mA)



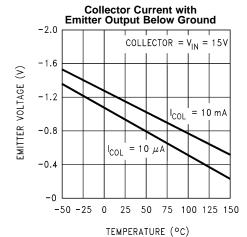


Figure 13.



TEST CIRCUIT*

Parameter tests can be made using the test circuit shown. Select the desired V_{in} , collector voltage and duty cycle with adjustable power supplies. A digital volt meter with an input resistance greater than 100 M Ω should be used to measure the following:

Input Reference Voltage to Ground; S1 in either position.

Level Shift Accuracy (%) = $(T_{P3}(V)/1V) \times 100\%$; S1 at $I_1 = I_2 = 1$ mA

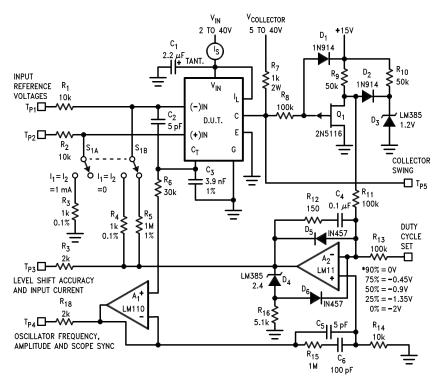
Input Current (mA) = $(1V - T_{p3}(V))/1 \text{ M}\Omega$: S1 at $I_1 = I_2 = 0 \text{ mA}$.

Oscillator parameters can be measured at T_{p4} using a frequency counter or an oscilloscope.

The Current Limit Sense Voltage is measured by connecting an adjustable 0-to-1V floating power supply in series with the current limit terminal and referring it to either the ground or the V_{in} terminal. Set the duty cycle to 90% and monitor test point T_{P5} while adjusting the floating power supply voltage until the LM2578A's duty cycle just reaches 0%. This voltage is the Current Limit Sense Voltage.

The Supply Current should be measured with the duty cycle at 0% and S1 in the $I_1 = I_2 = 0$ mA position.

*LM2578A specifications are measured using automated test equipment. This circuit is provided for the customer's convenience when checking parameters. Due to possible variations in testing conditions, the measured values from these testing procedures may not match those of the factory.



Op amp supplies are ±15V DVM input resistance >100 MΩ *LM2578 max duty cycle is 90%

Definition of Terms

Input Reference Voltage: The voltage (referred to ground) that must be applied to either the inverting or non-inverting input to cause the regulator switch to change state (ON or OFF).

Input Reference Current: The current that must be drawn from either the inverting or non-inverting input to cause the regulator switch to change state (ON or OFF).



Input Level Shift Accuracy: This specification determines the output voltage tolerance of a regulator whose output control depends on drawing equal currents from the inverting and non-inverting inputs (see the Inverting Regulator of Figure 34, and the RS-232 Line Driver Power Supply of Figure 36).

Level Shift Accuracy is tested by using two equal-value resistors to draw current from the inverting and non-inverting input terminals, then measuring the percentage difference in the voltages across the resistors that produces a controlled duty cycle at the switch output.

Collector Saturation Voltage: With the inverting input terminal grounded thru a 10 k Ω resistor and the output transistor's emitter connected to ground, the Collector SaturationVoltage is the collector-to-emitter voltage for a given collector current.

Emitter Saturation Voltage: With the inverting input terminal grounded thru a 10 k Ω resistor and the output transistor's collector connected to V_{in} , the Emitter Saturation Voltage is the collector-to-emitter voltage for a given emitter current.

Collector Emitter Sustaining Voltage: The collector-emitter breakdown voltage of the output transistor, measured at a specified current.

Current Limit Sense Voltage: The voltage at the Current Limit pin, referred to either the supply or the ground terminal, which (via logic circuitry) will cause the output transistor to turn OFF and resets cycle-by-cycle at the oscillator frequency.

Current Limit Sense Current: The bias current for the Current Limit terminal with the applied voltage equal to the Current Limit Sense Voltage.

Supply Current: The IC power supply current, excluding the current drawn through the output transistor, with the oscillator operating.

Functional Description

The LM2578A is a pulse-width modulator designed for use as a switching regulator controller. It may also be used in other applications which require controlled pulse-width voltage drive.

A control signal, usually representing output voltage, fed into the LM2578A's comparator is compared with an internally-generated reference. The resulting error signal and the oscillator's output are fed to a logic network which determines when the output transistor will be turned ON or OFF. The following is a brief description of the subsections of the LM2578A.

COMPARATOR INPUT STAGE

The LM2578A's comparator input stage is unique in that both the inverting and non-inverting inputs are available to the user, and both contain a 1.0V reference. This is accomplished as follows: A 1.0V reference is fed into a modified voltage follower circuit (see FUNCTIONAL DIAGRAM). When both input pins are open, no current flows through R1 and R2. Thus, both inputs to the comparator will have the potential of the 1.0V reference, V_A . When one input, for example the non-inverting input, is pulled ΔV away from V_A , a current of $\Delta V/R1$ will flow through R1. This same current flows through R2, and the comparator sees a total voltage of $2\Delta V$ between its inputs. The high gain of the system, through feedback, will correct for this imbalance and return both inputs to the 1.0V level.

This unusual comparator input stage increases circuit flexibility, while minimizing the total number of external components required for a voltage regulator system. The inverting switching regulator configuration, for example, can be set up without having to use an external op amp for feedback polarity reversal (see TYPICAL APPLICATIONS).

OSCILLATOR

The LM2578A provides an on-board oscillator which can be adjusted up to 100 kHz. Its frequency is set by a single external capacitor, C₁, as shown in Figure 14, and follows the equation

$$f_{OSC} = 8 \times 10^{-5} / C_1$$

The oscillator provides a blanking pulse to limit maximum duty cycle to 90%, and a reset pulse to the internal circuitry.

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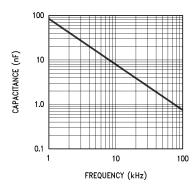


Figure 14. Value of Timing Capacitor vs Oscillator Frequency

OUTPUT TRANSISTOR

The output transistor is capable of delivering up to 750 mA with a saturation voltage of less than 0.9V. (see Collector Saturation Voltage and Emitter Saturation Voltage curves).

The emitter must not be pulled more than 1V below ground (this limit is 0.6V for T₁ ≥ 100°C). Because of this limit, an external transistor must be used to develop negative output voltages (see the Inverting Regulator Typical Application). Other configurations may need protection against violation of this limit (see the Emitter Output section of the Applications Information).

CURRENT LIMIT

The LM2578A's current limit may be referenced to either the ground or the V_{in} pins, and operates on a cycle-bycycle basis.

The current limit section consists of two comparators: one with its non-inverting input referenced to a voltage 110 mV below V_{in}, the other with its inverting input referenced 110 mV above ground (see FUNCTIONAL DIAGRAM). The current limit is activated whenever the current limit terminal is pulled 110 mV away from either V_{in} or ground.

Applications Information

CURRENT LIMIT

As mentioned in the functional description, the current limit terminal may be referenced to either the V_{in} or the ground terminal. Resistor R3 converts the current to be sensed into a voltage for current limit detection.

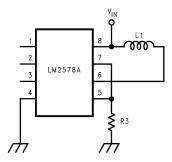


Figure 15. Current Limit, Ground Referred



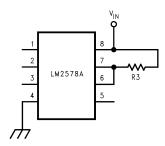


Figure 16. Current Limit, Vin Referred

CURRENT LIMIT TRANSIENT SUPPRESSION

When noise spikes and switching transients interfere with proper current limit operation, R1 and C1 act together as a low pass filter to control the current limit circuitry's response time.

Because the sense current of the current limit terminal varies according to where it is referenced, R1 should be less than 2 k Ω when referenced to ground, and less than 100 Ω when referenced to V_{in} .

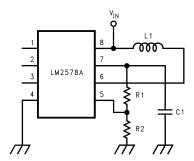


Figure 17. Current Limit Transient Suppressor, Ground Referred

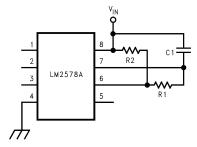


Figure 18. Current Limit Transient Suppressor, Vin Referred

C.L. SENSE VOLTAGE MULTIPLICATION

When a larger sense resistor value is desired, the voltage divider network, consisting of R1 and R2, may be used. This effectively multiplies the sense voltage by (1 + R1/R2). Also, R1 can be replaced by a diode to increase current limit sense voltage to about 800 mV (diode $V_f + 110$ mV).



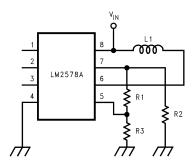


Figure 19. Current Limit Sense Voltage Multiplication, Ground Referred

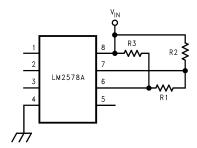


Figure 20. Current Limit Sense Voltage Multiplication, Vin Referred

UNDER-VOLTAGE LOCKOUT

Under-voltage lockout is accomplished with few external components. When Vin becomes lower than the zener breakdown voltage, the output transistor is turned off. This occurs because diode D1 will then become forward biased, allowing resistor R3 to sink a greater current from the non-inverting input than is sunk by the parallel combination of R1 and R2 at the inverting terminal. R3 should be one-fifth of the value of R1 and R2 in parallel.

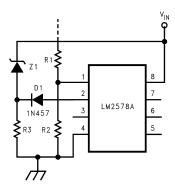


Figure 21. Under-Voltage Lockout

MAXIMUM DUTY CYCLE LIMITING

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The maximum duty cycle can be externally limited by adjusting the charge to discharge ratio of the oscillator capacitor with a single external resistor. Typical values are 50 µA for the charge current, 450 µA for the discharge current, and a voltage swing from 200 mV to 750 mV. Therefore, R1 is selected for the desired charging and discharging slopes and C1 is readjusted to set the oscillator frequency.



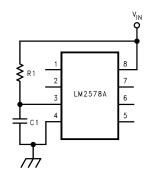


Figure 22. Maximum Duty Cycle Limiting

DUTY CYCLE ADJUSTMENT

When manual or mechanical selection of the output transistor's duty cycle is needed, the cirucit shown below may be used. The output will turn on with the beginning of each oscillator cycle and turn off when the current sunk by R2 and R3 from the non-inverting terminal becomes greater than the current sunk from the inverting terminal.

With the resistor values as shown, R3 can be used to adjust the duty cycle from 0% to 90%.

When the sum of R2 and R3 is twice the value of R1, the duty cycle will be about 50%. C1 may be a large electrolytic capacitor to lower the oscillator frequency below 1 Hz.

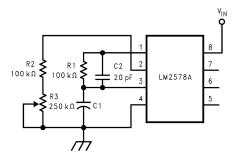


Figure 23. Duty Cycle Adjustment

REMOTE SHUTDOWN

The LM2578A may be remotely shutdown by sinking a greater current from the non-inverting input than from the inverting input. This may be accomplished by selecting resistor R3 to be approximately one-half the value of R1 and R2 in parallel.

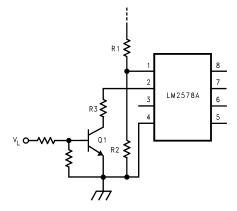


Figure 24. Shutdown Occurs when V_L is High



EMITTER OUTPUT

When the LM2578A output transistor is in the OFF state, if the Emitter output swings below the ground pin voltage, the output transistor will turn ON because its base is clamped near ground. The *Collector Current with Emitter Output Below Ground* curve shows the amount of Collector current drawn in this mode, vs temperature and Emitter voltage. When the Collector-Emitter voltage is high, this current will cause high power dissipation in the output transistor and should be avoided.

This situation can occur in the high-current high-voltage buck application if the Emitter output is used and the catch diode's forward voltage drop is greater than 0.6V. A fast-recovery diode can be added in series with the Emitter output to counter the forward voltage drop of the catch diode (see Figure 15). For better efficiency of a high output current buck regulator, an external PNP transistor should be used as shown in Figure 29.

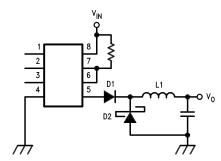


Figure 25. D1 Prevents Output Transistor from Improperly Turning ON due to D2's Forward Voltage

SYNCHRONIZING DEVICES

When several devices are to be operated at once, their oscillators may be synchronized by the application of an external signal. This drive signal should be a pulse waveform with a minimum pulse width of 2 μ s. and an amplitude from 1.5V to 2.0V. The signal source must be capable of 1.) driving capacitive loads and 2.) delivering up to 500 μ A for each LM2578A.

Capacitors C1 thru CN are to be selected for a 20% slower frequency than the synchronization frequency.

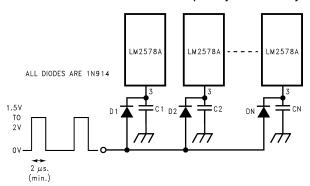


Figure 26. Synchronizing Devices

Typical Applications

The LM2578A may be operated in either the continuous or the discontinuous conduction mode. The following applications (except for the Buck-Boost Regulator) are designed for continuous conduction operation. That is, the inductor current is not allowed to fall to zero. This mode of operation has higher efficiency and lower EMI characteristics than the discontinuous mode.

Product Folder Links: LM2578A LM3578A



BUCK REGULATOR

The buck configuration is used to step an input voltage down to a lower level. Transistor Q1 in Figure 27 chops the input DC voltage into a squarewave. This squarewave is then converted back into a DC voltage of lower magnitude by the low pass filter consisting of L1 and C1. The duty cycle, D, of the squarewave relates the output voltage to the input voltage by the following equation:

$$V_{out} = D \times V_{in} = V_{in} \times (t_{on})/(t_{on} + t_{off}).$$

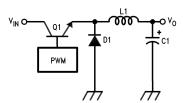


Figure 27. Basic Buck Regulator

Figure 28 is a 15V to 5V buck regulator with an output current, I_o , of 350 mA. The circuit becomes discontinuous at 20% of $I_{o(max)}$, has 10 mV of output voltage ripple, an efficiency of 75%, a load regulation of 30 mV (70 mA to 350 mA) and a line regulation of 10 mV (12 $\leq V_{in} \leq$ 18V).

Component values are selected as follows:

$$R1 = (V_0 - 1) \times R2$$
 where $R2 = 10 \text{ k}\Omega$

 $R3 = V/I_{sw(max)}$

 $R3 = 0.15\Omega$

where:

V is the current limit sense voltage, 0.11V

 $I_{sw(max)}$ is the maximum allowable current thru the output transistor.

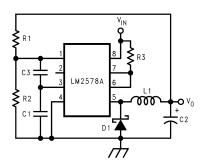
L1 is the inductor and may be found from the inductance calculation chart (Figure 29) as follows:

Given
$$V_{in} = 15V$$

 $V_{o} = 5V$
 $I_{o(max)} = 350 \text{ mA}$
 $f_{OSC} = 50 \text{ kHz}$
Discontinuous at 20% of $I_{o(max)}$.

Note that since the circuit will become discontinuous at 20% of I_{o(max)}, the load current must not be allowed to fall below 70 mA.





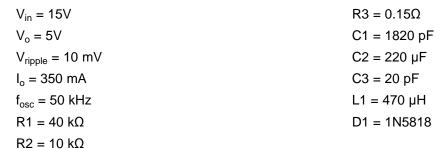


Figure 28. Buck or Step-Down Regulator

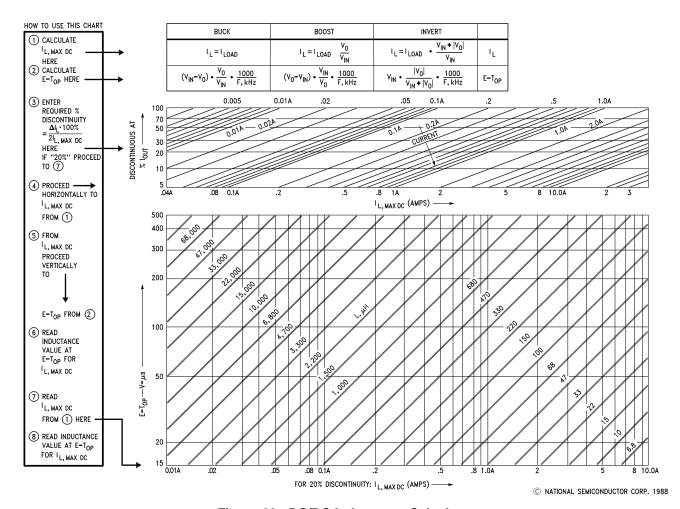


Figure 29. DC/DC Inductance Calculator



Step 1: Calculate the maximum DC current through the inductor, $I_{L(max)}$. The necessary equations are indicated at the top of the chart and show that $I_{L(max)} = I_{o(max)}$ for the buck configuration. Thus, $I_{L(max)} = 350$ mA.

Step 2: Calculate the inductor Volts-sec product, E-T_{op}, according to the equations given from the chart. For the Buck:

$$E-T_{op} = (V_{in} - V_o) (V_o/V_{in}) (1000/f_{osc})$$

$$=(15-5)(5/15)(1000/50)$$

$$= 66V-\mu s.$$

with the oscillator frequency, fosc, expressed in kHz.

Step 3: Using the graph with axis labeled "Discontinuous At % I_{OUT} " and " $I_{L(max, DC)}$ " find the point where the desired maximum inductor current, $I_{L(max, DC)}$ intercepts the desired discontinuity percentage.

In this example, the point of interest is where the 0.35A line intersects with the 20% line. This is nearly the midpoint of the horizontal axis.

Step 4: This last step is merely the translation of the point found in Step 3 to the graph directly below it. This is accomplished by moving straight down the page to the point which intercepts the desired E- T_{op} . For this example, E- T_{op} is 66V- μ s and the desired inductor value is 470 μ H. Since this example was for 20% discontinuity, the bottom chart could have been used directly, as noted in step 3 of the chart instructions.

For a full line of standard inductor values, contact Pulse Engineering (San Diego, Calif.) regarding their PE526XX series, or A. I. E. Magnetics (Nashville, Tenn.).

A more precise inductance value may be calculated for the Buck, Boost and Inverting Regulators as follows:

BUCK

$$L = V_o (V_{in} - V_o)/(\Delta I_L V_{in} f_{osc})$$

BOOST

$$L = V_{in} (V_o - V_{in})/(\Delta I_L f_{osc} V_o)$$

INVERT

$$L = V_{in} |V_o|/[\Delta I_L(V_{in} + |V_o|)f_{osc}]$$

where ΔI_{L} is the current ripple through the inductor. ΔI_{L} is usually chosen based on the minimum load current expected of the circuit. For the buck regulator, since the inductor current I_{L} equals the load current I_{O} ,

$$\Delta I_L = 2 \bullet I_{O(min)}$$

 $\Delta I_1 = 140$ mA for this circuit. ΔI_1 can also be interpreted as

$$\Delta I_1 = 2 \bullet (Discontinuity Factor) \bullet I_1$$

where the Discontinuity Factor is the ratio of the minimum load current to the maximum load current. For this example, the Discontinuity Factor is 0.2.

The remainder of the components of Figure 28 are chosen as follows:

C1 is the timing capacitor found in Figure 14.

$$C2 \ge V_o (V_{in} - V_o)/(8f_{osc}^2 V_{in} V_{ripple} L1)$$

where V_{ripple} is the peak-to-peak output voltage ripple.

C3 is necessary for continuous operation and is generally in the 10 pF to 30 pF range.

D1 should be a Schottky type diode, such as the 1N5818 or 1N5819.

BUCK WITH BOOSTED OUTPUT CURRENT

For applications requiring a large output current, an external transistor may be used as shown in Figure 30. This circuit steps a 15V supply down to 5V with 1.5A of output current. The output ripple is 50 mV, with an efficiency of 80%, a load regulation of 40 mV (150 mA to 1.5A), and a line regulation of 20 mV (12V \leq V_{in} \leq 18V).



Component values are selected as outlined for the buck regulator with a discontinuity factor of 10%, with the addition of R4 and R5:

$$R4 = 10V_{BE1}B_f/I_D$$

$$R5 = (V_{in} - V - V_{BE1} - V_{sat}) B_f/(I_{L(max, DC)} + I_{R4})$$

where:

 V_{BE1} is the V_{BE} of transistor Q1.

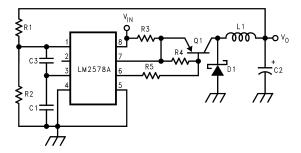
 V_{sat} is the saturation voltage of the LM2578A output transistor.

V is the current limit sense voltage.

 B_f is the forced current gain of transistor Q1 (B_f = 30 for Figure 30).

$$I_{R4} = V_{BE1}/R4$$

$$I_p = I_{L(max. DC)} + 0.5\Delta I_L$$



$V_{in} = 15V$	$R4 = 200\Omega$
$V_o = 5V$	$R5 = 330\Omega$
$V_{ripple} = 50 \text{ mV}$	C1 = 1820 pF
$I_0 = 1.5A$	C2 = 330 µF
$f_{\rm osc} = 50 \text{ kHz}$	C3 = 20 pF
$R1 = 40 \text{ k}\Omega$	L1 = 220 μH
$R2 = 10 \text{ k}\Omega$	D1 = 1N5819
$R3 = 0.05\Omega$	Q1 = D45

Figure 30. Buck Converter with Boosted Output Current

BOOST REGULATOR

The boost regulator converts a low input voltage into a higher output voltage. The basic configuration is shown in Figure 31. Energy is stored in the inductor while the transistor is on and then transferred with the input voltage to the output capacitor for filtering when the transistor is off. Thus,

$$V_o = V_{in} + V_{in}(t_{on}/t_{off}).$$

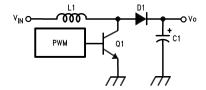


Figure 31. Basic Boost Regulator

The circuit of Figure 32 converts a 5V supply into a 15V supply with 150 mA of output current, a load regulation of 14 mV (30 mA to 140 mA), and a line regulation of 35 mV (4.5V \leq V_{in} \leq 8.5V).



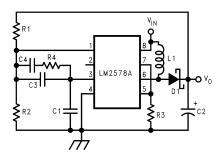




Figure 32. Boost or Step-Up Regulator

R1 = $(V_0 - 1)$ R2 where R2 = 10 kΩ.

$$R3 = V/(I_{L(max, DC)} + 0.5 \Delta I_{L})$$

where:

 $\Delta I_L = 2(I_{LOAD(min)})(V_o/V_{in})$

 ΔI_L is 200 mA in this example.

R4, C3 and C4 are necessary for continuous operation and are typically 220 k Ω , 20 pF, and 0.0022 μ F respectively.

C1 is the timing capacitor found in Figure 14.

$$C2 \ge I_o (V_o - V_{in})/(f_{osc} V_o V_{ripple}).$$

D1 is a Schottky type diode such as a 1N5818 or 1N5819.

L1 is found as described in the buck converter section, using the inductance chart for Figure 29 for the boost configuration and 20% discontinuity.

INVERTING REGULATOR

Figure 33 shows the basic configuration for an inverting regulator. The input voltage is of a positive polarity, but the output is negative. The output may be less than, equal to, or greater in magnitude than the input. The relationship between the magnitude of the input voltage and the output voltage is $V_o = V_{in} \times (t_{on}/t_{off})$.

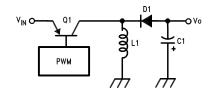


Figure 33. Basic Inverting Regulator

Figure 34 shows an LM2578A configured as a 5V to -15V polarity inverter with an output current of 300 mA, a load regulation of 44 mV (60 mA to 300 mA) and a line regulation of 50 mV (4.5V \leq V_{in} \leq 8.5V).

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$$\begin{split} &R1 = (|V_o| + 1) \; R2 \; where \; R2 = 10 \; k\Omega. \\ &R3 = V/(I_{L(max, \; DC)} + 0.5 \; \Delta I_L). \\ &R4 = 10 V_{BE1} B_f/(I_{L \; (max, \; DC)} + 0.5 \; \Delta I_L) \end{split}$$

where:

V, V_{BE1}, V_{sat}, and B_f are defined in the Buck Converter with Boosted Output Current section.

$$\Delta I_{L} = 2(I_{LOAD(min)})(V_{in} + |V_{o}|)/V_{IN}$$

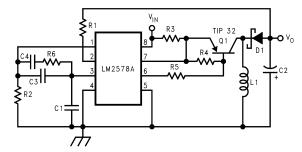
R5 is defined in the Buck Converter with Boosted Output Current section.

R6 serves the same purpose as R4 in the Boost Regulator circuit and is typically 220 k Ω .

C1, C3 and C4 are defined in the Boost Regulator section.

$$C2 \ge I_o |V_o|/[f_{osc}(|V_o| + V_{in}) |V_{ripple}]$$

L1 is found as outlined in the section on buck converters, using the inductance chart of Figure 29 for the invert configuration and 20% discontinuity.



$V_{in} = 5V$	$R4 = 190\Omega$
$V_0 = -15V$	$R5 = 82\Omega$
$V_{ripple} = 5 \text{ mV}$	$R6 = 220 \text{ k}\Omega$
$I_0 = 300 \text{ mA}$	C1 = 1820 pF
$I_{min} = 60 \text{ mA}$	$C2 = 1000 \mu F$
$f_{osc} = 50 \text{ kHz}$	C3 = 20 pF
$R1 = 160 \text{ k}\Omega$	$C4 = 0.0022 \ \mu F$
$R2 = 10 \text{ k}\Omega$	L1 = 150 µH
$R3 = 0.01\Omega$	D1 = 1N5818

Figure 34. Inverting Regulator

BUCK-BOOST REGULATOR

The Buck-Boost Regulator, shown in Figure 35, may step a voltage up or down, depending upon whether or not the desired output voltage is greater or less than the input voltage. In this case, the output voltage is 12V with an input voltage from 9V to 15V. The circuit exhibits an efficiency of 75%, with a load regulation of 60 mV (10 mA to 100 mA) and a line regulation of 52 mV.

$$R1 = (V_o - 1) R2$$
 where $R2 = 10 k\Omega$

$$R3 = V/0.75A$$

R4, C1, C3 and C4 are defined in the Boost Regulator section.

D1 and D2 are Schottky type diodes such as the 1N5818 or 1N5819.

$$C2 \geq \frac{\left(I_{O}/V_{ripple}\right)\left(V_{O} + 2V_{d}\right)}{\left[f_{osc}\left(V_{in} + V_{O} + 2V_{d} - V_{sat} - V_{sat1}\right)\right]}$$



where:

V_d is the forward voltage drop of the diodes.

V_{sat} is the saturation voltage of the LM2578A output transistor.

V_{sat1} is the saturation voltage of transistor Q1.

$$L1 \ge (V_{in} - V_{sat} - V_{sat1}) (t_{on}/l_p) \tag{1}$$

where:

$$\begin{split} t_{on} &= \frac{(1/f_{osc}) \left(V_{o} + 2V_{d}\right)}{(V_{o} + V_{in} + 2V_{d} - V_{sat} - V_{sat1})} \\ I_{p} &= \frac{2I_{o} \left(V_{in} + V_{o} + 2V_{d} - V_{sat} - V_{sat1}\right)}{(V_{in} - V_{sat} - V_{sat1})} \end{split}$$

RS-232 LINE DRIVER POWER SUPPLY

The power supply, shown in Figure 36, operates from an input voltage as low as 4.2V (5V nominal), and delivers an output of $\pm 12V$ at ± 40 mA with better than 70% efficiency. The circuit provides a load regulation of ± 150 mV (from 10% to 100% of full load) and a line regulation of ± 10 mV. Other notable features include a cycle-by-cycle current limit and an output voltage ripple of less than 40 mVp-p.

A unique feature of this circuit is its use of feedback from both outputs. This dual feedback configuration results in a sharing of the output voltage regulation by each output so that neither side becomes unbalanced as in single feedback systems. In addition, since both sides are regulated, it is not necessary to use a linear regulator for output regulation.

The feedback resistors, R2 and R3, may be selected as follows by assuming a value of 10 k Ω for R1;

$$R2 = (V_0 - 1V)/45.8 \mu A = 240 k\Omega$$

$$R3 = (|V_0| + 1V)/54.2 \,\mu A = 240 \,k\Omega$$

Actually, the currents used to program the values for the feedback resistors may vary from 40 μ A to 60 μ A, as long as their sum is equal to the 100 μ A necessary to establish the 1V threshold across R1. Ideally, these currents should be equal (50 μ A each) for optimal control. However, as was done here, they may be mismatched in order to use standard resistor values. This results in a slight mismatch of regulation between the two outputs.

The current limit resistor, R4, is selected by dividing the current limit threshold voltage by the maximum peak current level in the output switch. For our purposes R4 = 110 mV/750 mA = 0.15Ω . A value of 0.1Ω was used.

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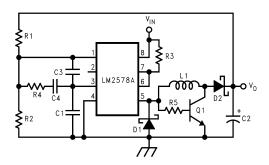
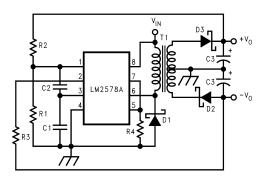




Figure 35. Buck-Boost Regulator



$V_{in} = 5V$	$R4 = 0.15\Omega$
V _o ±12V	C1 = 820 pF
$I_0 = \pm 40 \text{ mA}$	C2 = 10 pF
$f_{\rm osc} = 80 \text{ kHz}$	C3 = 220 µF
$R1 = 10 \text{ k}\Omega$	D1, D2, D3 = 1N5819
$R2 = 240 \text{ k}\Omega$	T1 = PE-64287
P3 - 240 kO	

Figure 36. RS-232 Line Driver Power Supply

Capacitor C1 sets the oscillator frequency and is selected from Figure 14.

Capacitor C2 serves as a compensation capacitor for synchronous operation and a value of 10 to 50 pF should be sufficient for most applications.

Product Folder Links: LM2578A LM3578A



A minimum value for an ideal output capacitor C3, could be calculated as $C = I_o \times t/\Delta V$ where I_o is the load current, t is the transistor on time (typically 0.4/f_{osc}), and ΔV is the peak-to-peak output voltage ripple. A larger output capacitor than this theoretical value should be used since electrolytics have poor high frequency performance. Experience has shown that a value from 5 to 10 times the calculated value should be used.

For good efficiency, the diodes must have a low forward voltage drop and be fast switching. 1N5819 Schottky diodes work well.

Transformer selection should be picked for an output transistor "on" time of 0.4/f_{osc}, and a primary inductance high enough to prevent the output transistor switch from ramping higher than the transistor's rating of 750 mA. Pulse Engineering (San Diego, Calif.) and Renco Electronics, Inc. (Deer Park, N.Y.) can provide further assistance in selecting the proper transformer for a specific application need. The transformer used in Figure 36 was a Pulse Engineering PE-64287.

9-Mar-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
LM2578AM	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 125	2578 AM	Samples
LM2578AM/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	2578 AM	Samples
LM2578AMX	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	-40 to 125	2578 AM	Samples
LM2578AMX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	2578 AM	Samples
LM2578AN	ACTIVE	PDIP	Р	8	40	TBD	Call TI	Call TI	-40 to 125	LM2578AN	Samples
LM2578AN/NOPB	ACTIVE	PDIP	Р	8	40	Green (RoHS & no Sb/Br)	Call TI	Level-1-NA-UNLIM	-40 to 125	LM2578AN	Samples
LM3578AM	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	0 to 125	3578 AM	Samples
LM3578AM/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 125	3578 AM	Samples
LM3578AMX	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	0 to 125	3578 AM	Samples
LM3578AMX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 125	3578 AM	Samples
LM3578AN	ACTIVE	PDIP	Р	8	40	TBD	Call TI	Call TI	0 to 125	LM3578AN	Samples
LM3578AN/NOPB	ACTIVE	PDIP	Р	8	40	Green (RoHS & no Sb/Br)	Call TI	Level-1-NA-UNLIM	0 to 125	LM3578AN	Samples

⁽¹⁾ The marketing status values are defined as follows:

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LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

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TBD: The Pb-Free/Green conversion plan has not been defined.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



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9-Mar-2013

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(4) Only one of markings shown within the brackets will appear on the physical device.

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	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All differsions are norminal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2578AMX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2578AMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM3578AMX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM3578AMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2578AMX	SOIC	D	8	2500	349.0	337.0	45.0
LM2578AMX/NOPB	SOIC	D	8	2500	349.0	337.0	45.0
LM3578AMX	SOIC	D	8	2500	349.0	337.0	45.0
LM3578AMX/NOPB	SOIC	D	8	2500	349.0	337.0	45.0

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

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